

福靈有限公司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD, KWUN TONG, KOWLOON, HONG KONG.

TEL: 852-2790 0314 FAX: 852-2790 0206

Philips Semiconductors

Product specification

General purpose diodes

BAS19; BAS20; BAS21

FEATURES

- · Small plastic SMD package
- · Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 100 V; 150 V; 200 V
- Repetitive peak reverse voltage: max. 120 V; 200 V; 250 V
- · Repetitive peak forward current: max. 625 mA.

APPLICATIONS

General purpose switching in e.g. surface mounted circuits.

DESCRIPTION

The BAS19, BAS20 and BAS21 are general purpose diodes fabricated in planar technology, and encapsulated in a small SOT23 plastic SMD package.

MARKING

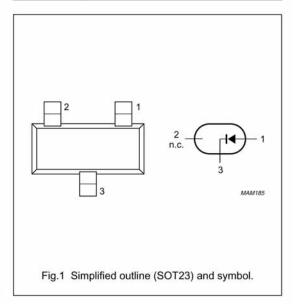
TYPE NUMBER	MARKING CODE (1)		
BAS19	JP*		
BAS20	JR*		
BAS21	JS*		

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PINNING

PIN	DESCRIPTION	
1	anode	
2	not connected	
3	cathode	





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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BAS19		-	120	V
	BAS20		-	200	V
	BAS21		-	250	V
V _R	continuous reverse voltage				
	BAS19		.=	100	V
	BAS20		-	150	V
	BAS21		-	200	V
lF	continuous forward current	see Fig.2; note 1	=	200	mA
I _{FRM}	repetitive peak forward current		-	625	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	-	9	Α
		t = 100 μs	_	3	Α
		t = 10 ms	-	1.7	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.



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ELECTRICAL CHARACTERISTICS

T_i = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	see Fig.3		
		I _F = 100 mA	1	V
		I _F = 200 mA	1.25	V
I _R	reverse current	see Fig.5		
BAS19 BAS20	BAS19	V _R = 100 V	100	nA
		V _R = 100 V; T _j = 150 °C	100	μА
	BAS20	V _R = 150 V	100	nA
		V _R = 150 V; T _j = 150 °C	100	μА
	BAS21	V _R = 200 V	100	nA
	1, 34, 54, 54, 54, 54, 54	V _R = 200 V; T _j = 150 °C	100	μА
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	5	pF
t _{rr}	reverse recovery time	when switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA; see Fig.8	50	ns

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		330	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on an FR4 printed-circuit board.



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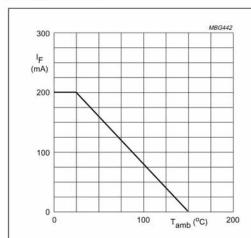
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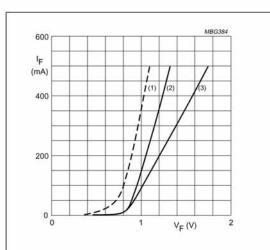
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GRAPHICAL DATA



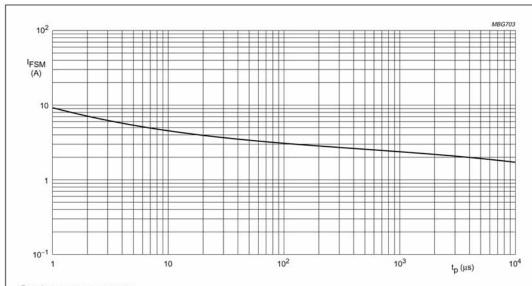
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) T_j = 150 °C; typical values.
- (2) T_j = 25 °C; typical values.
- (3) T_j = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents.

 $T_j = 25$ °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.



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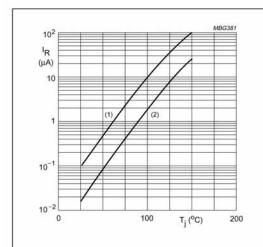
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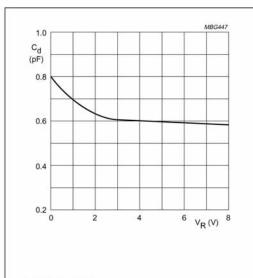
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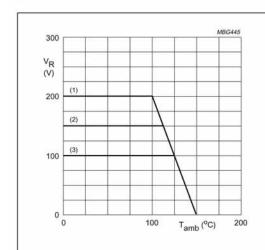
- (1) V_R = V_{Rmax}; maximum values.
- (2) V_R = V_{Rmax}; typical values.

Fig.5 Reverse current as a function of junction temperature.



f = 1 MHz; T_j = 25 °C.

Fig.6 Diode capacitance as a function of reverse voltage; typical values.



- (1) BAS21.
- (2) BAS20.
- (3) BAS19.

Fig.7 Maximum permissible continuous reverse voltage as a function of the ambient temperature.



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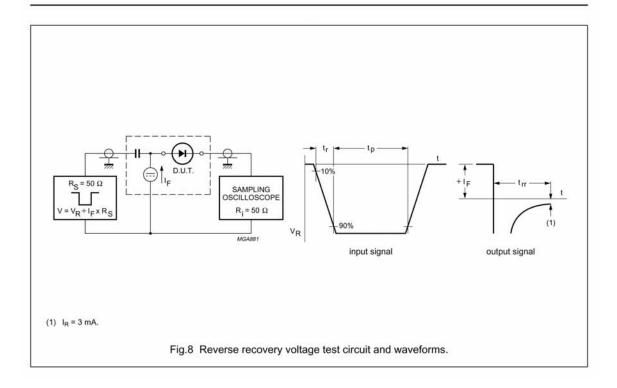
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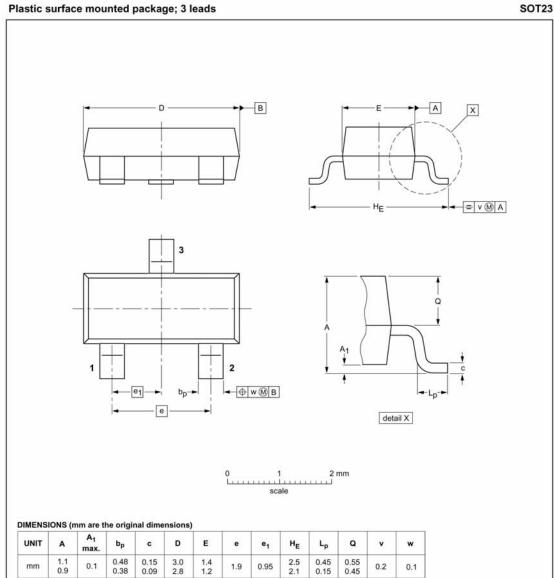
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PACKAGE OUTLINE

SOT23



OUTLINE		REFERENCES		EUROPEAN	ICCUIT DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT23		TO-236AB			97-02-28 99-09-13



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II Preliminary data Qualification		Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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